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Broadband Wavelength Filter Device using Sidewall Grating for Filtering Optical Signals IITM Technology Available for Licensing

Problem Statement

- Generally, the Silicon-on-Insulator waveguides has a compact design and prominent wavelength dependent characteristics with sub-wavelength grating which makes the SOI waveguides sought after in many applications.
- Further many SOI waveguides are used like multilayer interference filters. In conventional filters, the fundamental mode of the optical signal is passed along with the **unwanted** higher order modes, leading to **loss of power & causing signal interference**.
- In conventional DBR filters broad band pass wavelength response is not possible.
- Hence, there is a need to address above issues in efficient manner.

Technology Category/Market

Technology: Broadband Wavelength Filter Device with grating structure;

Industry: Electronic Hardware, ICT, Photonics; Application: Semiconductor, Optoelectronics; Market: The global filter market by wavelength is projected to reach \$158.76B by 2030, at a CAGR of 8.22% during (2023-2030)

Technology

- Present invention describes a Broadband wavelength filter device, and a method for fabricating said broadband wavelength filter device for filtering optical signals.
- Said broadband wavelength filter device comprises a buried oxide layer, a silicon layer over the buried oxide layer;
- Moreover, said silicon layer comprises an input & output waveguide and an optical filtering portion and input & output taper region.
- Said Input waveguide and output waveguide is used to operate in a **fundamental mode of transverse electric** (TE) field.
- Further, the optical filtering portion is to operate in the fundamental mode and a first order mode.
- Input & output taper region filters out higher order leaky modes leading to remove loss of power & signal interference.

 The below smart chart along with figure describes the steps involved in the proposed method for **fabricating** a broadband wavelength filter device for filtering optical signals. (Refer Figs.2 & 3)





Intellectual Property

IITM IDF Ref. 1466; Patent No:410136; PCT Application No. PCT/IN2017/050403

TRL (Technology Readiness Level)

TRL-2/3, Proof of concept tested in Lab;

Research Lab

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Key Features / Value Proposition

* Technical Perspective & Industrial Perspective:

- Provide a broadband wavelength filter device, & the waveguide structure over the buried oxide (SiO_2) is **unique** & it comprises multimode waveguide, wherein the distributed Bragg grating (DBR) structure describes the optical filtering portion which is configured in between two single mode input, & output waveguides. (Refer Fig. 1)
- Using **sidewall grating** for filtering optical signals.

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- Provide an optical filtering portion in the broadband wavelength filter device, with periodic perturbations on one side such that the **optical filtering portion** supports at least **two modes** i.e., a fundamental mode & a first order mode, which couples back with forward propagating fundamental mode thus resulting broadband filter response. However, propagating further in **backward direction**, it travel through taper region followed by single mode input waveguide, hence removing higher order leaky mode which in turn remove interference & signal cluttering. Hence, facilitates said device to filter higher order leaky modes.
- Advantageous in obtaining all the power in the fundamental mode of the transverse electric mode & neglects the power in the first order mode.
- Applicable as a broad band pass wavelength filter in an on chip optical WDM networking system/Raman spectroscopy.



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